



RoHS

HALOGEN

FREE GREEN

Standard SMD LED PLCC-2



DESCRIPTION

These devices have been designed to meet the increasing demand for surface mounting technology.

The package of the VLM.310. is the PLCC-2.

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

PRODUCT GROUP AND PACKAGE DATA

Product group: LED
Package: SMD PLCC-2
Product series: standard
Angle of half intensity: ± 60°

FEATURES

- SMD LEDs with exceptional brightness
- · Luminous intensity categorized
- · Compatible with automatic placement equipment
- EIA and ICE standard package
- Compatible with infrared, vapor phase and wave solder processes according to CECC 00802 and J-STD-020



- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit I_{Vmax.}/I_{Vmin.} ≤ 1.6
- Preconditioning according to JEDEC[®] level 2a
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Telecommunication: indicator and backlighting in telephone and fax
- · Indicator and backlight for audio and video equipment
- · Indicator and backlight in office equipment
- Flat backlight for LCDs, switches, and symbols
- General use

PARTS TABLE														
PART	COLOR		JMINOU ITENSIT (mcd)		at I _F	WA	VELEN(nm)	GTH	at I _F		ORWAF OLTAG (V)		at I _F	TECHNOLOGY
		MIN.	TYP.	MAX.	(IIIA)	MIN.	TYP.	MAX	MAX (mA)	MIN.	TYP.	MAX	(IIIA)	
VLMH3100-GS08	Amber	2.8	12	-	10	612	619	625	10	-	2	2.8	20	GaAsP on GaP
VLMH3100-GS18	Amber	2.8	12	-	10	612	619	625	10	-	2	2.8	20	GaAsP on GaP
VLMH3102-GS08	Amber	7.1	12	18	10	612	619	625	10	-	2	2.8	20	GaAsP on GaP
VLMO3100-GS08	Soft orange	2.8	8	-	10	598	605	611	10	-	2	2.8	20	GaAsP on GaP
VLMY3100-GS08	Yellow	2.8	11		10	581	588	594	10	-	2.1	2.8	20	GaAsP on GaP
VLMY3101-GS08	Yellow	4.5	10	11.2	10	581	588	594	10	-	2.1	2.8	20	GaAsP on GaP
VLMY3102-GS08	Yellow	7.1	11	18	10	581	588	594	10	-	2.1	2.8	20	GaAsP on GaP
VLMG3100-GS08	Green	4.5	16	-	10	562	572	575	10	-	2.1	2.8	20	GaP on GaP
VLMG3100-GS18	Green	4.5	16	-	10	562	572	575	10	-	2.1	2.8	20	GaP on GaP
VLMG3102-GS08	Green	11.2	16	18	10	562	572	575	10	-	2.1	2.8	20	GaP on GaP
VLMG3105-GS08	Green	7.1	16	18	10	562	572	575	10	-	2.1	2.8	20	GaP on GaP

VLMH310., VLMO310., VLMY310., VLMG310.

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ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25$ °C, unless otherwise specified) VLMG310., VLMH310., VLMY310.					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V_{R}	6	V	
DC forward current	T _{amb} ≤ 74 °C	I _F	20	mA	
Surge forward current	t _p ≤ 10 μs	I _{FSM}	0.34	А	
Power dissipation		P _V	56	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	-40 to +100	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C	
Thermal resistance junction to ambient	Mounted on PC board (pad size > 16 mm ²)	R_{thJA}	400	K/W	

OPTICAL AND ELECTRICAL CHARACTERISTICS ($T_{amb} = 25 ^{\circ}\text{C}$, unless otherwise specified) VLMH310., AMBER							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity (1)	I _E = 10 mA	VLMH3100	I _V	2.8	12	-	mcd
	IF = TO THA	VLMH3102	I _V	7.1	12	18	mcd
Dominant wavelength	I _F = 10 mA		λ_{d}	612	619	625	nm
Peak wavelength	I _F = 10 mA		λ_{p}	-	635	-	nm
Angle of half intensity	I _F = 10 mA		φ	-	± 60	-	0
Forward voltage	I _F = 20 mA		V _F	-	2	2.8	V
Reverse current	V _R = 6 V		I _R	-	-	10	μΑ
Junction capacitance	V _R = 0 V, f = 1 MHz		Cj	-	15	-	pF

Note

⁽¹⁾ In one packing unit $I_{Vmax.}/I_{Vmin.} \le 1.6$

OPTICAL AND ELECTRICAL CHARACTERISTICS ($T_{amb} = 25 ^{\circ}C$, unless otherwise specified) VLMO310., SOFT ORANGE							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity (1)	I _F = 10 mA	VLMO3100	I _V	2.8	8	-	mcd
Dominant wavelength	I _F = 10 mA		λ_{d}	598	605	611	nm
Peak wavelength	I _F = 10 mA		λ_{p}	-	605	-	nm
Angle of half intensity	I _F = 10 mA		φ	-	± 60	-	٥
Forward voltage	I _F = 20 mA		V _F	-	2	2.8	V
Reverse current	V _R = 6 V		I _R	-	-	10	μA
Junction capacitance	V _R = 0 V, f = 1 MHz		C _j	-	15	-	pF

Note

 $^{(1)}~$ In one packing unit $I_{Vmax.}/I_{Vmin.} \leq 1.6$

VLMH310., VLMO310., VLMY310., VLMG310.

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OPTICAL AND ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) VLMY310., YELLOW							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		VLMY3100	I _V	2.8	11		mcd
Luminous intensity (1)	$I_F = 10 \text{ mA}$	VLMY3101	I _V	4.5	10	11.2	mcd
		VLMY3102	I _V	7.1	11	18	mcd
Dominant wavelength	I _F = 10 mA		λ_{d}	581	588	594	nm
Peak wavelength	I _F = 10 mA		λ_{p}	-	585	-	nm
Angle of half intensity	I _F = 10 mA		φ	-	± 60	-	0
Forward voltage	I _F = 20 mA		V_{F}	-	2.1	2.8	V
Reverse current	V _R = 6 V		I _R	-	-	10	μΑ
Junction capacitance	$V_D = 0 \text{ V f} = 1 \text{ MHz}$		C:	_	15	_	рF

Note

 $^{^{(1)}}$ In one packing unit $I_{Vmax.}/I_{Vmin.} \leq 1.6$

OPTICAL AND ELECTRICAL CHARACTERISTICS ($T_{amb} = 25 ^{\circ}C$, unless otherwise specified) VLMG310., GREEN							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity (1)		VLMG3100	Ι _V	4.5	16	-	mcd
	$I_F = 10 \text{ mA}$	VLMG3102	Ι _V	11.2	16	18	mcd
		VLMG3105	Ι _V	7.1	16	18	mcd
Dominant wavelength	I _F = 10 mA		λ_{d}	562	572	575	nm
Peak wavelength	I _F = 10 mA		λ_{p}	-	565	-	nm
Angle of half intensity	I _F = 10 mA		φ	-	± 60	-	0
Forward voltage	I _F = 20 mA		V_{F}	-	2.1	2.8	V
Reverse current	V _R = 6 V		I _R	-	-	10	μΑ
Junction capacitance	V _R = 0 V, f = 1 MHz		-	-	15	-	pF

Note

 $^{^{(1)}~}$ In one packing unit $I_{Vmax.}/I_{Vmin.} \leq 1.6$

OLOR CALS	SSIFICATION						
	YEL	YELLOW		EEN	SOFT ORANGE		
GROUP		DOM. WAVE	LENGTH (nm)		DOM. WAVE	LENGTH (nm)	
	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
0	-	-	-	-	-	-	
1	581	584	-	-	598	601	
2	583	586	-	-	600	603	
3	585	588	-	-	602	605	
4	587	590	564	567	604	607	
5	589	592	566	569	606	609	
6	591	594	568	571	608	611	
7	-	-	570	573	-	-	
8	-	-	572	575	-	-	

Note

· Wavelengths are tested at a current pulse duration of 25 ms



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LUMINOUS INTENSITY CLASSIFICATION							
GROUP	LIGHT INTENSITY (mcd)						
STANDARD	OPTIONAL	MIN.	MAX.				
F	1	1.12	1.40				
Г	2	1.40	1.80				
G	1	1.80	2.24				
g	2	2.24	2.80				
Н	1	2.80	3.55				
П	2	3.55	4.50				
J	1	4.50	5.60				
7	2	5.60	7.10				
К	1	7.10	9.00				
K	2	9.00	11.20				
	1	11.20	14.00				
L	2	14.00	18.00				
М	1	18.00	22.40				
	2	22.40	28.00				

Note

 Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.

In order to ensure availability, single wavelength groups will not be orderable

CROSSING TABLE		
VISHAY	OSRAM	STANLEY
VLMH3100	-	-
VLMH3101	-	-
VLMH3102	-	-
VLMO3100	LOT670J1L2	-
VLMO3101	LOT670J1K2	-
VLMY3100	LYT670J1L2	-
VLMY3101	LYT670J1K2	-
VLMY3102	LYT670K1L2	-
VLMG3100	LGT670K1M2	VYBG1104B
VLMG3102	LGT670L1L2	-
VLMG3105	LGT671K1L2	-

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

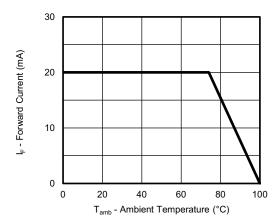


Fig. 1 - Maximum Permissible Forward Current vs.
Ambient Temperature

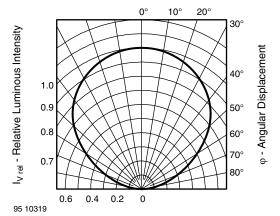


Fig. 2 - Relative Luminous Intensity vs. Angular Displacement

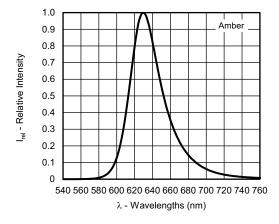


Fig. 3 - Relative Intensity vs. Wavelength

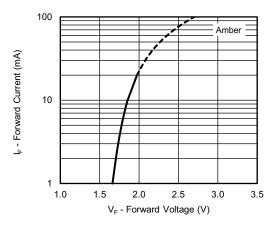


Fig. 4 - Forward Current vs. Forward Voltage

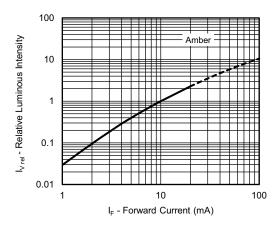


Fig. 5 - Relative Luminous Intensity vs. Forward Current

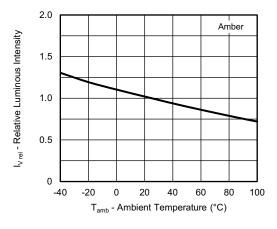


Fig. 6 - Relative Luminous Intensity vs. Ambient Temperature

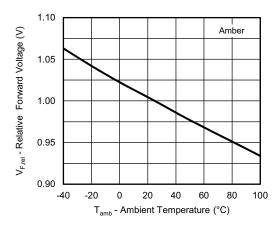


Fig. 7 - Relative Forward Voltage vs. Ambient Temperature

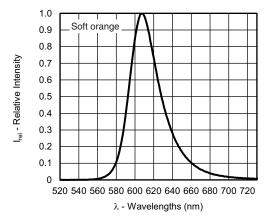


Fig. 8 - Relative Intensity vs. Wavelength

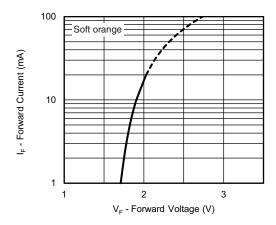


Fig. 9 - Forward Current vs. Forward Voltage

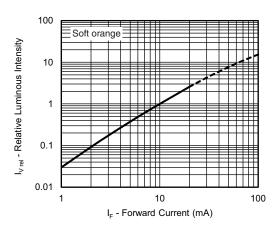


Fig. 10 - Relative Luminous Intensity vs. Forward Current

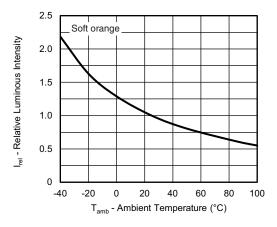


Fig. 11 - Relative Luminous Intensity vs. Ambient Temperature

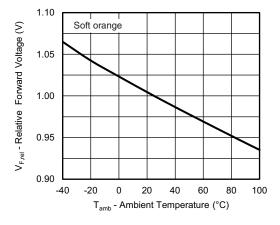


Fig. 12 - Relative Forward Voltage vs. Ambient Temperature

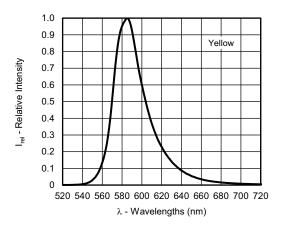


Fig. 13 - Relative Intensity vs. Wavelength

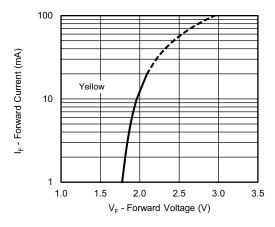


Fig. 14 - Forward Current vs. Forward Voltage

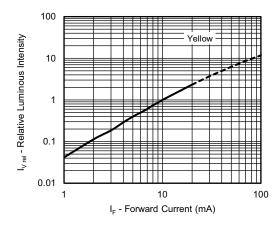


Fig. 15 - Relative Luminous Intensity vs. Forward Current

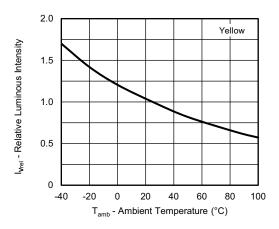


Fig. 16 - Relative Luminous Intensity vs Ambient Temperature

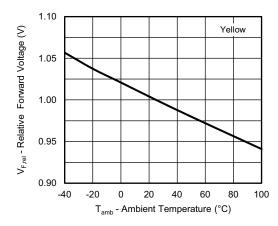


Fig. 17 - Relative Forward Voltage vs. Ambient Temperature

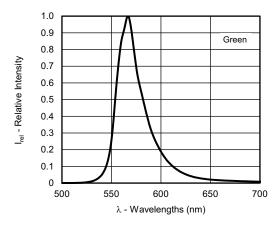


Fig. 18 - Relative Intensity vs. Wavelength

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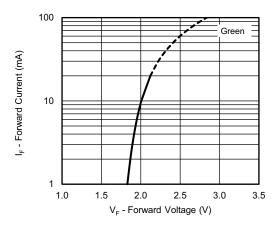


Fig. 19 - Forward Current vs. Forward Voltage

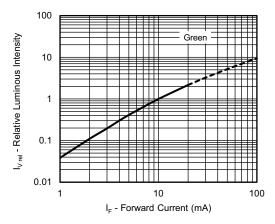


Fig. 20 - Relative Luminous Intensity vs. Forward Current

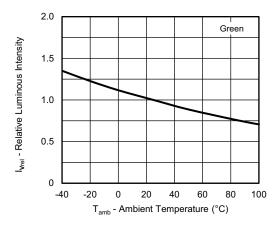


Fig. 21 - Relative Luminous Intensity vs. Ambient Temperature

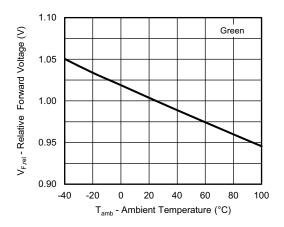


Fig. 22 - Relative Forward Voltage vs. Ambient Temperature

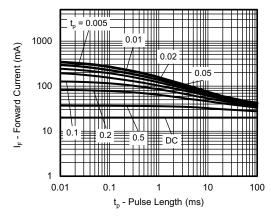
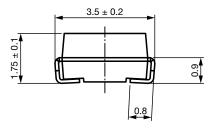
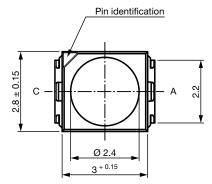


Fig. 23 - Permissible Pulse Forward Current vs. Pulse Duration

PACKAGE DIMENSIONS in millimeters

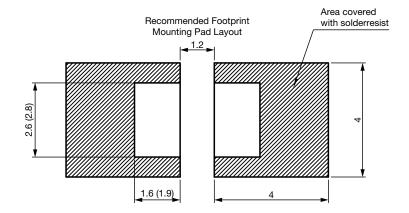






Drawing-No.: 6.541-5067.01-4

Issue: 7; 12.03.14

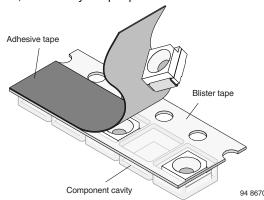


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METHOD OF TAPING / POLARITY AND TAPE AND REEL

SMD LED (VLM.3-SERIES)

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



TAPING OF VLM.3...

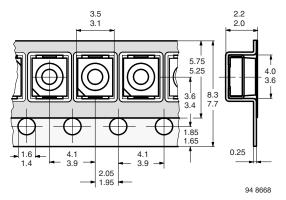


Fig. 24 - Tape Dimensions in mm for PLCC-2

REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDS, TAPE OPTION GS08 (= 1500 PCS.)

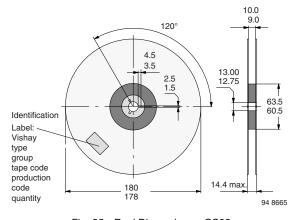


Fig. 25 - Reel Dimensions - GS08

REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDS, TAPE OPTION GS18 (= 8000 PCS.) PREFERRED

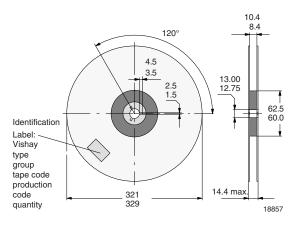


Fig. 26 - Reel Dimensions - GS18

SOLDERING PROFILE

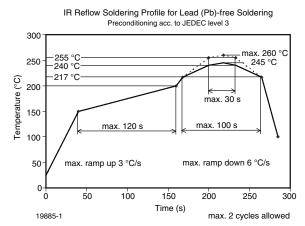


Fig. 27 - Vishay Lead (Pb)-free Reflow Soldering Profile (according to J-STD-020)

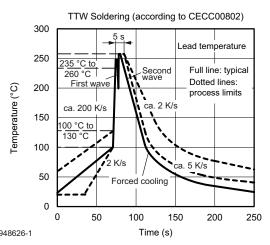
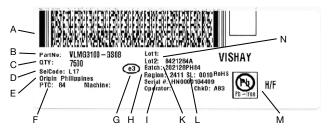


Fig. 28 - Double Wave Soldering of Opto Devices (all packages)



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BAR CODE PRODUCT LABEL (example)



A. 2D barcode

B. Part No: Vishay part number

C. QTY: quantity

D. SelCode: selection bin code

E. Country of origin

F. PTC: production plant code

G. Termination finish

H. Region code

I. Serial#: serial number

K. Batch Number: year, week, country code, plant code

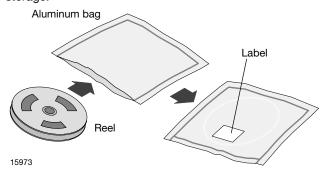
L. SL: storage location

M. Environmental Symbols: RoHS, lead (Pb)-free, halogen

N. Lot numbers

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

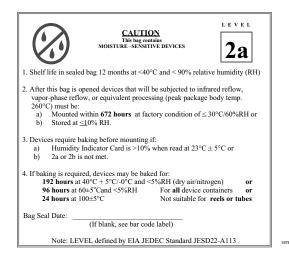
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C / - 0 °C and < 5 % RH (dry air / nitrogen) or

96 h at 60 °C + 5 °C and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electrostatic sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABEL

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.



Legal Disclaimer Notice

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